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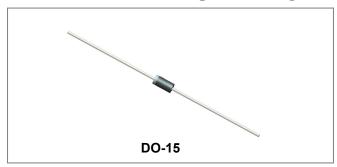








# FR151G THRU FR157G FAST RECOVERY RECTIFIERS



#### **Features**

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Mechanical Data**

- Case: JEDEC DO-15 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- · Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.014 ounce, 0.40 grams

#### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristic	Symbol	FR 151G	FR 152G	FR 153G	FR 154G	FR 155G	FR 156G	FR 157G	Units
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	<b>V</b>
Maximum average forward rectified current 0.375"(9.5mm) lead length at $T_A$ =55 $^{\circ}$ C	I <sub>(AV)</sub>	1.5			Α				
Peak forward surge current 8.3ms single half sinewave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	50			А				
Maximum instantaneous forward voltage at 1.5A	V <sub>F</sub>	1.3			V				
Maximum DC reverse current $T_A$ =25 $^{\circ}$ C at rated DC blocking voltage $T_A$ =100 $^{\circ}$ C	I <sub>R</sub>	5.0 100.0				μA			
Maximum Reverse Recovery Time (Note 1)	Trr	150 250 500		00	ns				
Typical Junction Capacitance (Note 2)	CJ	25			pF				
Typical Thermal Resistance (Note 3)	R <sub>θJA</sub>	50.0			°C/W				
Junction Temperature	TJ	-65 to +150			°C				
Storage Temperature Range	T <sub>STG</sub>	-65 to +150		°C					

#### \*Glass passivated forms are available upon request

- Note: 1. Reverse recovery condition IF=0.5A, IR=1.0A, Irr=0.25A
  - 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
  - 3. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length, P.C.B. mounted
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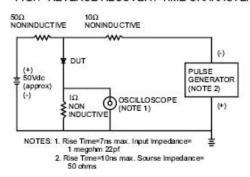






#### **Ratings and Characteristics Curves**

FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



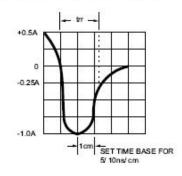
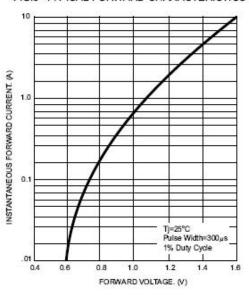


FIG.3- TYPICAL FORWARD CHARACTERISTICS



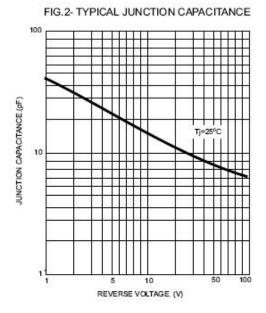


FIG.5- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

50

40

Tj=55°C

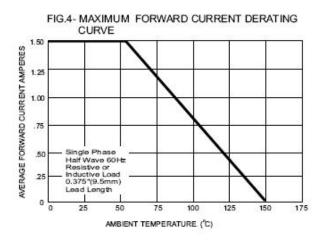
Tj=55°C

10

8.3ms Single Half Sine Wave JEDEC Method

1 2 4 6 8 10 20 40 60 80 100

NUMBER OF CYCLES AT 60Hz



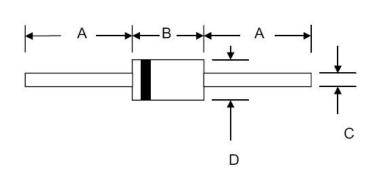
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#### **Mechanical Dimensions DO-15**



SYMBOL	Millim	neters	Inches			
O'IMBOL	Min.	Max.	Min.	Max.		
А	25.4	-	1.000	-		
В	5.5	7.62	0.217	0.300		
С	0.7	0.9	0.028	0.034		
D	2.6	3.6	0.104	0.140		

### **Ordering Information**

Device	Package	Shipping		
FR151G-FR157G	DO-15 (Pb-Free)	3000pcs /tape		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**

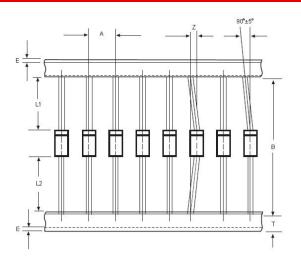


Where XXXXX is YYWWL

FR151G = Part Name
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

# **Carrier Tape Specification DO-15**



SYMBOL	Millimeters			
	Min.	Max.		
А	4.50	5.50		
В	50.9	53.9		
Z	-	1.20		
Т	5.60	6.40		
E	-	0.80		
IL1-L2I	-	1.0		

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